

<<基于硅技术24GHz汽车雷达的微波>>

图书基本信息

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内容概要

基于硅技术24GHz汽车雷达的微波电路介绍了设计、实现微波电路以及CMOS和SiGe双极技术的微波接收器电路特性。

基于硅技术24GHz汽车雷达的微波电路所介绍的电路设计适用于汽车工业应用技术，如车道变换辅助系统以及报警器等。

基于硅技术24GHz汽车雷达的微波电路适合相关专业研究生以及高年级本科生使用。

书籍目录

1 IntroductionReferences2 Radar Systems2.1 Radar Principle2.2 Radar Equation and System Considerations2.3 CW and Frequency-Modulated Radar2.3.1 Doppler Radar2.3.2 Frequency-Modulated Radar2.3.2.1 Linear FM Continuous-Wave Radar2.4 Angle Detection2.5 Frequency Regulations2.6 Receiver Architectures2.6.1 Homodyne2.6.2 Heterodyne2.7 Status of Automotive Radar Systems2.8 Technology Requirements for Radar ChipsetReferences3 CMOS and Bipolar Technologies3.1 CMOS Technology3.1.1 MOSFET Layout and Modeling Considerations3.1.2 Devices Available in C11N3.2 Bipolar Transistors3.2.1 HBT Layout and Modeling Considerations3.2.2 Devices Available in B7HF2003.3 Technology Comparison3.3.1 Transistor Performance3.3.2 Metallization and Passive ComponentsReferences4 Modeling Techniques4.1 Analytical Fitting of On-Chip Inductors4.1.1 Series Branch Parameters Fitting4.1.2 Shunt Branches Parameters Fitting4.1.3 Results Verification4.2 Transistor Finger Capacitance EstimationReferences5 Measurement Techniques5.1 S-parameter De-embedding Techniques5.1.1 Extension of Thru Technique for De-embedding of Asymmetrical Error Networks5.1.1.1 Theory5.1.1.2 Result Verification5.1.2 De-embedding of Differential Devices using cascade-based Two-Port Techniques5.1.2.1 Theory5.1.2.2 Result Verification5.2 Differential Measurements using Baluns5.2.1 Theoretical Analysis5.2.1.1 Back-to-BackMeasurement5.2.1.2 DUT Measurement5.2.1.3 Insertion Loss De-embedding Error5.2.2 Measurement VerificationReferences6 Radar Receiver Circuits6.1 Low-Noise Amplifiers6.1.1 LNA in CMOS Technology6.1.2 LNA in SiGe:C Technology6.1.3 Measurements of CMOS and SiGe LNAs6.1.4 LNA Results Summary and Comparison6.2 Mixers6.2.1 Active Mixers6.2.1.1 Active Mixer in CMOS Technology6.2.1.2 Active Mixer in SiGe Technology6.2.1.3 Measurements of CMOS and SiGe Active Mixers6.2.1.4 Active Mixers Results Summary and Comparison6.2.2 Passive Mixers6.2.2.1 Passive Resistive Ring Mixer in CMOS Technology6.2.2.2 Passive Bipolar Mixer in SiGe Technology6.2.2.3 Measurements of CMOS and SiGe Passive Mixers6.2.2.4 Passive Mixers Results Summary and Comparison6.2.3 Comparison of Active and Passive Mixers6.3 Single-Channel Receivers6.3.1 Design of Active and Passive Receivers in CMOS6.3.2 Receiver Measurements and Analysis6.3.2.1 Chip Size6.3.2.2 Power Consumption, Gain and Noise Figure6.3.2.3 Linearity6.3.2.4 Required LO Power6.3.2.5 Isolation6.3.2.6 Temperature Performance6.3.3 Receiver Results Summary and Comparison6.4 IQ Receivers6.4.1 Design of IQ Receivers6.4.1.1 IQ Receiver in CMOS Technology6.4.1.2 IQ Receiver in SiGe Technology6.4.2 IQ Receiver Measurements6.4.3 IQ Receiver Results Summary and Comparison6.5 Integrated Passive Circuits6.5.1 Circuit Design and Layout Considerations6.5.1.1 On-Chip 180°Power Splitter/Combiner6.5.1.2 On-Chip 90°Power Splitter/Combiner6.5.1.3 On-Chip 180°Hybrid Ring Coupler6.5.2 Realization and Measurement Results6.5.2.1 On-Chip 180°Power Splitter/Combiner6.5.2.2 On-Chip 90°Power Splitter/Combiner6.5.2.3 On-Chip 180°Hybrid Ring Coupler6.5.3 Results Summary and Discussion6.6 Circuit-Level RF ESD Protection6.6.1 Overview of Circuit-Level Protection Techniques6.6.2 Virtual Ground Concept6.6.2.1 Concept Verification by Circuit Simulation6.6.2.2 Concept Verification by HBM Measurement6.6.2.3 Concept Verification by TLP Measurement6.6.3 Transformer Protection Concept6.6.3.1 Test LNA Circuit Design6.6.3.2 Test LNA Realization and Measurement6.6.3.3 Concept Verification by TLP MeasurementReferences7 Radar Transceiver Circuits7.1 IQ Transceiver in CMOS7.1.1 IQ Transceiver Circuit Design7.1.2 Measurements of Transceiver7.1.3 Results Summary and Comparison7.2 Merged Power-Amplifier-Mixer Transceiver7.2.1 System Considerations7.2.2 Power-Amplifier-Mixer Circuit Design7.2.3 PAMIX Measurements7.2.4 Results Summary and ComparisonReferences8 Conclusions and OutlookA LFM CW RadarReferencesB FSCW RadarReferencesC Surface Charge MethodC.1 Surface Charge Method TheoryC.2 Meshing of the Multifinger LayoutD Measurement of Active CircuitsD.1 Measurement TechniquesD.2 LNA CharacterizationD.2.1 S-parameter MeasurementD.2.2 Noise Figure MeasurementD.2.3 Linearity MeasurementD.3 Mixer and Receiver CharacterizationD.3.1 Conversion Gain MeasurementD.3.2 Noise Figure MeasurementD.3.3 Linearity MeasurementReferencesIndex

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